# Precision Monolithic Quad SPST CMOS Analog Switches 

## DESCRIPTION

The DG417B, DG418B, DG419B monolithic CMOS analog switches were designed to provide high performance switching of analog signals. Combining low power, low leakages, high speed, low on-resistance and small physical size, the DG417B series is ideally suited for portable and battery powered industrial and military applications requiring high performance and efficient use of board space.

To achieve high-voltage ratings and superior switching performance, the DG417B series is built on Vishay Siliconix's high voltage silicon gate (HVSG) process. Break-before-make is guaranteed for the DG419B, which is an SPDT configuration. An epitaxial layer prevents latchup.
Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

The DG417B and DG418B respond to opposite control logic levels as shown in the Truth Table.

## FEATURES

- $\pm 15 \mathrm{~V}$ analog signal range
- On-resistance - $\mathrm{R}_{\mathrm{DS}(o n)}: 15 \Omega$
- Fast switching action - $\mathrm{t}_{\mathrm{ON}}$ : 110 ns
- TTL and CMOS compatible
- MSOP-8 and SOIC-8 package
- Compliant to RoHS directive 2002/95/EC


## BENEFITS

- Widest dynamic range
- Low signal errors and distortion
- Break-before-make switching action
- Simple interfacing
- Reduced board space
- Improved reliability


## APPLICATIONS

- Precision test equipment
- Precision instrumentation
- Battery powered systems
- Sample-and-hold circuits
- Military radios
- Guidance and control systems
- Hard disk drivers


## FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



| TRUTH TABLE |  |  |
| :---: | :---: | :---: |
| Logic | DG417B | DG418B |
| 0 | ON | OFF |
| 1 | OFF | ON |

Logic " 0 " $\leq 0.8 \mathrm{~V}$
Logic "1" $\geq 2.4 \mathrm{~V}$

| TRUTH TABLE - DG419B |  |  |
| :---: | :---: | :---: |
| Logic | SW $_{\mathbf{1}}$ | $\mathbf{S W}_{\mathbf{2}}$ |
| 0 | ON | OFF |
| 1 | OFF | ON |

Logic "0" $\leq 0.8 \mathrm{~V}$
Logic "1" $\geq 2.4 \mathrm{~V}$

* Pb containing terminations are not RoHS compliant, exemptions may apply

| ORDERING INFORMATION |  |  |
| :---: | :---: | :---: |
| Temp Range | Package | Part Number |
| DG417B, DG418B |  |  |
| $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ | 8-Pin Plastic MiniDIP | $\begin{gathered} \text { DG417BDJ } \\ \text { DG417BDJ-E3 } \end{gathered}$ |
|  |  | $\begin{gathered} \text { DG418BDJ } \\ \text { DG418BDJ-E3 } \end{gathered}$ |
|  | 8-Pin Narrow SOIC | DG417BDY DG417BDY-E3 DG417BDY-T1 DG417BDY-T1-E3 |
|  |  | DG418BDY DG418BDY-E3 DG418BDY-T1 DG418BDY-T1-E3 |
|  | 8-Pin MSOP | DG417BDQ-T1-E3 |
|  |  | DG418BDQ-T1-E3 |
| DG419B |  |  |
| $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ | 8-Pin Plastic MiniDIP | $\begin{gathered} \text { DG419BDJ } \\ \text { DG419BDJ-E3 } \end{gathered}$ |
|  | 8-Pin Narrow SOIC | DG419BDY DG419BDY-E3 DG419BDY-T1 DG419BDY-T1-E3 |
|  | 8-Pin MSOP | DG419BDQ-T1-E3 |


| ABSOLUTE MAXIMUM RATINGS |  |  |  |
| :---: | :---: | :---: | :---: |
| Parameter |  | Limit | Unit |
| V- |  | -20 | V |
| V+ |  | 20 |  |
| GND |  | 25 |  |
| $\mathrm{V}_{\mathrm{L}}$ |  | (GND - 0.3) to (V+) + 0.3 |  |
| Digital Inputs ${ }^{\text {a }}$, $\mathrm{V}_{\mathrm{S}}, \mathrm{V}_{\mathrm{D}}$ |  | $(\mathrm{V}-)-2 \mathrm{~V} \text { to }(\mathrm{V}+)+2$ <br> or 30 mA , whichever occurs first |  |
| Current, (Any Terminal) Continuous |  | 30 | mA |
| Current (S or D) Pulsed at 1 ms , 10 \% Duty Cycle |  | 100 |  |
| Storage Temperature |  | - 65 to 150 | ${ }^{\circ} \mathrm{C}$ |
| Power Dissipation (Package) ${ }^{\text {b }}$ | 8-Pin Plastic MiniDIP ${ }^{\text {c }}$ | 400 | mW |
|  | 8-Pin Narrow SOIC ${ }^{\text {c }}$ | 400 |  |
|  | 8 -Pin MSOP ${ }^{\text {d }}$ | 400 |  |
|  | 8-Pin CerDIP ${ }^{\text {e }}$ | 600 |  |

Notes:
a. Signals on $S_{X}, D_{X}$, or $I N_{X}$ exceeding $V+$ or $V$ - will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC board.
c. Derate $5.3 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $75^{\circ} \mathrm{C}$.
d. Derate $4 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $70^{\circ} \mathrm{C}$.
e. Derate $8 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $75^{\circ} \mathrm{C}$.

## SCHEMATIC DIAGRAM Typical Channel



Figure 1.

## SPECIFICATIONS ${ }^{\text {a }}$



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| Parameter |  | Test Conditions Unless Otherwise Specified$\begin{gathered} \mathrm{V}+=15 \mathrm{~V}, \mathrm{~V}-=-15 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{L}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=2.4 \mathrm{~V}, 0.8 \mathrm{~V}^{\mathrm{f}} \end{gathered}$ |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Symbol | Test Conditions Unless Otherwise Specified$\begin{gathered} \mathrm{V}_{+}=15 \mathrm{~V}, \mathrm{~V}-=-15 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{L}}=5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=2.4 \mathrm{~V}, 0.8 \mathrm{~V}^{\mathrm{f}} \end{gathered}$ |  | Temp. ${ }^{\text {b }}$ | Typ. ${ }^{\text {c }}$ | A Suffix <br> $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |  | D Suffix <br> $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ |  | Unit |
|  |  |  |  | Min. ${ }^{\text {d }}$ |  | Max. ${ }^{\text {d }}$ | Min. ${ }^{\text {d }}$ | Max ${ }^{\text {d. }}$ |  |
| Dynamic Characteristics |  |  |  |  |  |  |  |  |  |  |
| Source Off Capacitance ${ }^{\text {e }}$ | $\mathrm{C}_{\text {S(off) }}$ | $\mathrm{f}=1 \mathrm{MHz}, \mathrm{V}_{\mathrm{S}}=0 \mathrm{~V}$ |  |  |  | 12 |  |  |  |  | pF |
| Drain Off Capacitance ${ }^{\text {e }}$ | $\mathrm{C}_{\mathrm{D} \text { (off) }}$ |  | $\begin{array}{\|l} \hline \text { DG417B } \\ \text { DG418B } \end{array}$ | Room | 12 |  |  |  |  |  |  |
| Channel On Capacitance ${ }^{\text {e }}$ | $\mathrm{C}_{\mathrm{D} \text { (on) }}$ | $\mathrm{f}=1 \mathrm{MHz}, \mathrm{V}_{\mathrm{S}}=0 \mathrm{~V}$ | $\begin{aligned} & \text { DG417B } \\ & \text { DG418B } \\ & \hline \end{aligned}$ | Room | 50 |  |  |  |  |  |  |
|  |  |  | DG419B | Room | 57 |  |  |  |  |  |  |
| Power Supplies |  |  |  |  |  |  |  |  |  |  |  |
| Positive Supply Current | $1+$ | $\begin{gathered} \mathrm{V}_{+}=16.5 \mathrm{~V}, \mathrm{~V}-=-16.5 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{IN}}=0 \text { or } 5 \mathrm{~V} \end{gathered}$ |  | Room Full | 0.001 |  | $\begin{aligned} & 1 \\ & 5 \end{aligned}$ |  | $\begin{aligned} & 1 \\ & 5 \end{aligned}$ |  |  |
| Negative Supply Current | I- |  |  | $\begin{aligned} & \hline \text { Room } \\ & \text { Full } \end{aligned}$ | -0.001 | $\begin{aligned} & \hline-1 \\ & -5 \end{aligned}$ |  | $\begin{aligned} & \hline-1 \\ & -5 \end{aligned}$ |  |  |  |
| Logic Supply Current | IL |  |  | $\begin{array}{\|l\|} \hline \text { Room } \\ \text { Full } \end{array}$ | 0.001 |  | $\begin{aligned} & 1 \\ & 5 \end{aligned}$ |  | $\begin{aligned} & 1 \\ & 5 \end{aligned}$ | $\mu \mathrm{A}$ |  |
| Ground Current | $\mathrm{I}_{\text {GND }}$ |  |  | $\begin{array}{\|l\|} \hline \text { Room } \\ \text { Full } \end{array}$ | -0.001 | $\begin{aligned} & \hline-1 \\ & -5 \end{aligned}$ |  | $\begin{aligned} & -1 \\ & -5 \end{aligned}$ |  |  |  |


| SPECIFICATIONS ${ }^{\text {a }}$ |  |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Parameter | Symbol | Test Conditions Unless Otherwise Specified$\begin{gathered} \mathrm{V}+=12 \mathrm{~V}, \mathrm{~V}-=0 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{L}}=5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=2.4 \mathrm{~V}, 0.8 \mathrm{~V}^{\mathrm{f}} \end{gathered}$ |  | Temp. ${ }^{\text {b }}$ | Typ. ${ }^{\text {c }}$ | A Suffix$-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |  | $\begin{gathered} \text { D Suffix } \\ -40^{\circ} \mathrm{C} \text { to } 85^{\circ} \mathrm{C} \end{gathered}$ |  | Unit |
|  |  |  |  | Min. ${ }^{\text {d }}$ |  | Max. ${ }^{\text {d }}$ | Min. ${ }^{\text {d }}$ | Max. ${ }^{\text {d }}$ |  |
| Analog Switch |  |  |  |  |  |  |  |  |  |  |
| Analog Signal Range ${ }^{\text {e }}$ | $\mathrm{V}_{\text {ANALOG }}$ |  |  |  | Full |  | 0 | 12 | 0 | 12 | V |
| Drain-Source On-Resistance | $\mathrm{R}_{\mathrm{DS} \text { (on) }}$ | $\begin{gathered} I_{S}=-10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{D}}=3 \\ \mathrm{~V}+=10.8 \mathrm{~V} \end{gathered}$ |  | Room Full | 26 |  | $\begin{aligned} & 35 \\ & 52 \end{aligned}$ |  | $\begin{aligned} & 35 \\ & 45 \end{aligned}$ | $\Omega$ |
| Dynamic Characteristics |  |  |  |  |  |  |  |  |  |  |
| Turn-On Time | $\mathrm{t}_{\mathrm{ON}}$ | $\begin{gathered} \mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF} \\ \mathrm{~V}_{\mathrm{S}}=8 \mathrm{~V}, \text { See Switching } \\ \text { Time Test Circuit } \end{gathered}$ |  | Room Full | 100 |  | $\begin{aligned} & \hline 125 \\ & 155 \\ & \hline \end{aligned}$ |  | $\begin{aligned} & \hline 125 \\ & 143 \\ & \hline \end{aligned}$ | ns |
| Turn-Off Time | $\mathrm{t}_{\text {OFF }}$ |  |  | $\begin{array}{\|c\|} \hline \text { Room } \\ \text { Full } \end{array}$ | 38 |  | $\begin{aligned} & \hline 66 \\ & 73 \end{aligned}$ |  | $\begin{aligned} & \hline 66 \\ & 69 \end{aligned}$ |  |
| Break-Before-Make Time Delay | $t_{D}$ | $\mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ | DG419B | Room | 62 | 25 |  | 25 |  |  |
| Transition Time | ${ }^{\text {t }}$ trans | $\begin{array}{r} \mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=3 \mathrm{~g} \\ \mathrm{~V}_{\mathrm{S} 1}=0 \mathrm{~V}, 8 \mathrm{~V}, \mathrm{~V}_{\mathrm{S} 2}=8 \end{array}$ |  | Room Full | 95 |  | $\begin{aligned} & 119 \\ & 153 \end{aligned}$ |  | $\begin{aligned} & \hline 119 \\ & 141 \end{aligned}$ |  |
| Charge Injection | Q | $\mathrm{C}_{\mathrm{L}}=10 \mathrm{nF}, \mathrm{V}_{\text {gen }}=0 \mathrm{~V}, \mathrm{R}$ | = $=0 \Omega$ | Room | 18 |  |  |  |  | pC |
| Power Supplies |  |  |  |  |  |  |  |  |  |  |
| Positive Supply Current | I+ | $\begin{gathered} \mathrm{V}+=13.2 \mathrm{~V}, \mathrm{~V}_{\mathrm{L}}=5.25 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{IN}}=0 \text { or } 5 \mathrm{~V} \end{gathered}$ |  | Room Full | 0.001 |  | $\begin{aligned} & \hline 1 \\ & 5 \end{aligned}$ |  | 1 5 | $\mu \mathrm{A}$ |
| Negative Supply Current | I- |  |  | Room | -0.001 | $\begin{aligned} & \hline-1 \\ & -5 \\ & \hline \end{aligned}$ |  | $\begin{aligned} & \hline-1 \\ & -5 \\ & \hline \end{aligned}$ |  |  |
| Logic Supply Current | IL |  |  | Room | 0.001 |  | $\begin{aligned} & \hline 1 \\ & 5 \end{aligned}$ |  | 1 5 |  |
| Ground Current | $\mathrm{I}_{\text {GND }}$ |  |  | Room | -0.001 | -1 -5 |  | -1 -5 |  |  |

## Notes:

a. Refer to PROCESS OPTION FLOWCHART.
b. Room $=25^{\circ} \mathrm{C}$, full $=$ as determined by the operating temperature suffix.
c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
e. Guaranteed by design, not subject to production test.
f. $\mathrm{V}_{\text {IN }}=$ input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise noted


On-Resistance vs. $V_{D}$ and Unipolar Power Supply Voltage


On-Resistance vs. $\mathrm{V}_{\mathrm{D}}$ and Temperature



On-Resistance vs. $V_{D}$ and Dual Supply Voltage



## DG417B, DG418B, DG419B

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TYPICAL CHARACTERISTICS $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise noted


TYPICAL CHARACTERISTICS $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise noted


## TEST CIRCUITS

$\mathrm{V}_{\mathrm{O}}$ is the steady state output with the switch on.

$C_{L}$ (includes fixture and stray capacitance)

$$
V_{\mathrm{O}}=\mathrm{V}_{\mathrm{S}} \quad \frac{R_{\mathrm{L}}}{R_{\mathrm{L}}+R_{\mathrm{DS}(\mathrm{on})}}
$$



Note: Logic input waveform is inverted for switches that have the opposite logic sense.

Figure 2. Switching Time (DG417B/418B)

## TEST CIRCUITS



Figure 3. Break-Before-Make (DG419B)

$\mathrm{C}_{\mathrm{L}}$ (includes fixture and stray capacitance)

$$
\mathrm{V}_{\mathrm{O}}=\mathrm{V}_{\mathrm{S}} \quad \frac{\mathrm{R}_{\mathrm{L}}}{\mathrm{R}_{\mathrm{L}}+\mathrm{r}_{\mathrm{DS}(\mathrm{on})}}
$$

Figure 4. Transition Time (DG419B)


Figure 5. Charge Injection

## TEST CIRCUITS



Figure 6. Crosstalk


Off Isolation = $20 \log \left|\frac{\mathrm{~V}_{\mathrm{O}}}{\mathrm{V}_{\mathrm{S}}}\right|$

Figure 7. Off isolation


Figure 8. Insertion Loss


Figure 9. Source/Drain Capacitances

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